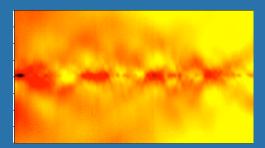
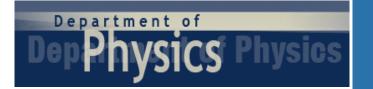
Chun Ning Lau (Jeanie)

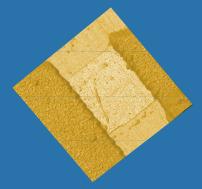
UNIVERSITY of CALIFORNIA Riverside

Phase Coherent Charge Transport in Graphene Billiards









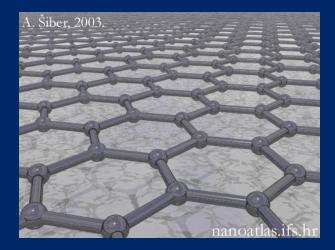
Outline

- Motivation
- Device fabrication
- Data and discussion

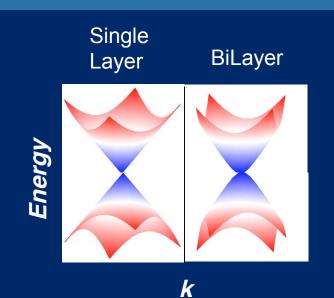
Normal
electrodesMinimum conductivity in grapheneBallistic, phase coherent transportSuperconduting
electrodesSuperconducting Proximity effectNovel plasmon-mediated superconductivity (?)

Conclusion and future work

Motivation



http://www.nanotech-now.com/Art_Gallery/antonio-siber.htm

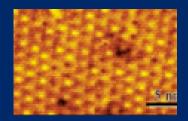


- Degeneracy of 2 sub-lattices
- Unique Dispersion Relations
- Massless Dirac Fermions --> Relativistic physics

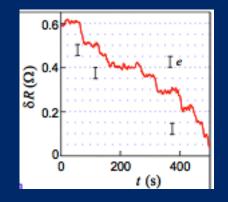
Potential Applications

- With advantages of carbon nanotubes

 high thermal conductivity,
 high current density
 - ✓ high mobility
- potentially compatible with lithographic techniques
- Chemical and biological sensors based on graphene
- Electronics, Spintronics, and Valley-tronics

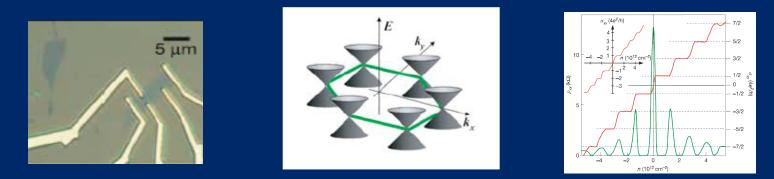


Epitaxially grown graphene Berger *et al*, *Science* (2006)



Ultra-sensitive gas sensors Schedin *et al*, preprint (2006).

Pioneering Work

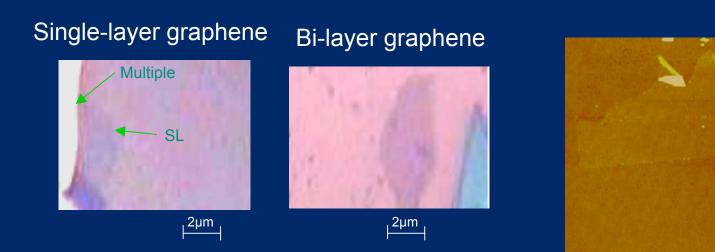


K. S. Novoselov et al, Science 2004; K. S. Novoselov et al, Nature 2005; Y. Zhang et al, Nature 2005.

- Graphene was isolated for the first time in 2004
- Observation of QHE $\sigma_{xy}=4(n+1/2)e^2/h$
- Linear energy-momentum relation of electrons- massless, relativistic Dirac fermions (v_F≈c/300)

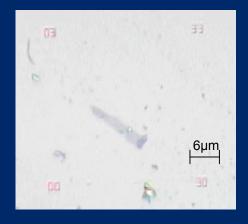
Our goal: to study graphene coupled to superconductors

Device Fabrication



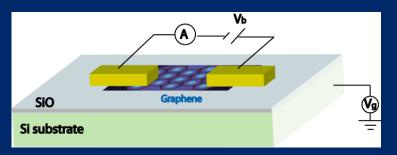
- Mechanical exfoliation -- rub natural graphite flakes onto SiO₂ substrate
- Identify the number of layers by color interference in optical microscope
- AFM images reveal mesoscopic features

Device Fabrication

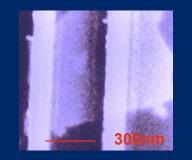


Two steps of E-beam lithography

- Alignment Marks
- Electrodes (10 nm Pd + 70 nm Al)

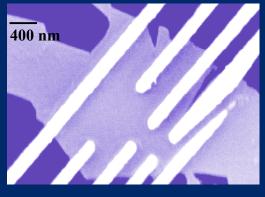


Bi-layer graphene device



2-Terminal geometry

Single-layer graphene device



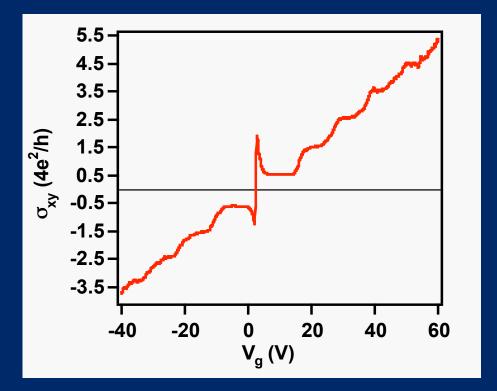
Hall bar geometry

January 11, 2007

Anomalous Quantum Hall Effect

Conductivity of single layer graphene quantized at half-integral values of $4e^2/h$

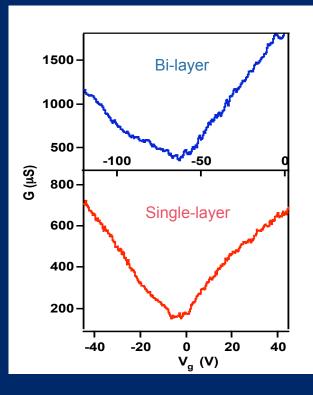
-> confirmed selection of single layer graphene

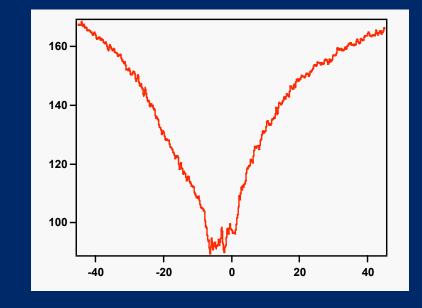


Measurement taken at B=8T and T=260mK

Bipolar Field Effect Transistor

T=1.5 K

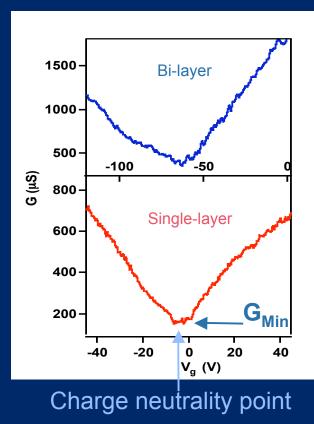


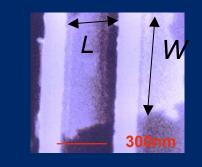


 Bipolar field effect observed in both single and bi-layer graphene devices

G-V_g frequently displays sub-linear relationship

Bipolar Field Effect Transistor



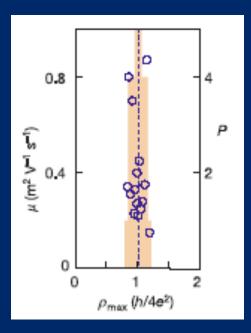


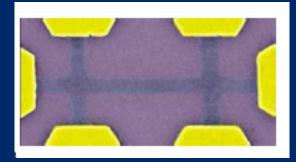
• At charge neutrality point $\rightarrow G_{min}$ minimum conductivity $\sigma_{min}=L/W G_{min}$

January 11, 2007

Minimum Conductivity – the mystery of missing π

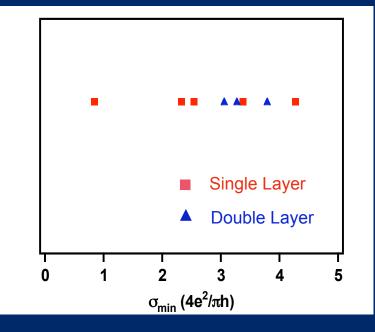
- Theoretical prediction: universal value of G_Q=4e²/πh, independent of v_F.
 Fradkin 1986; Lee 1983; Peres *et al* (2006), Nilsson *et al* (2006), Katsnelson (2006), Tworzydlo *et al* (2006).....
- Experimental measurements: 4e²/h
 (Novoselov et al, Nature, 2005.)

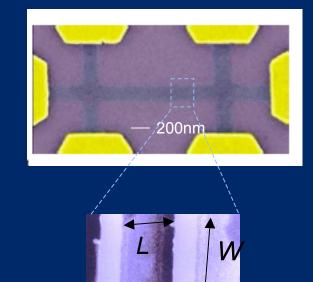




Minimum Conductivity – our data

• Our measured values of σ_{min} range from 0.8 to 4.3 G_Q .





Difference from previous experiments:
Smaller inter-electrode spacing (100 - 400 nm)
Larger aspect ratio *W/L*

Minimum Conductivity

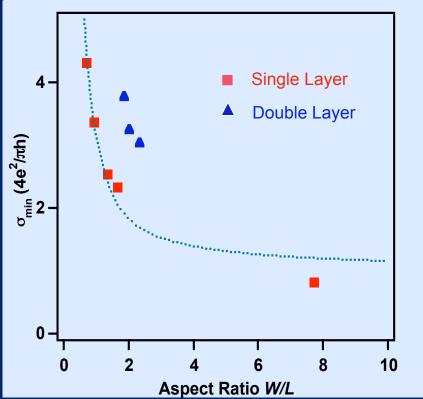
– shedding light on the mystery of missing π

Tworzydlo et al, PRL, 2006:

- $\sigma_{\rm min}$ depends on devices' aspect ratio $\it W/L$ for a ballistic piece of graphene

 $T_n = \frac{1}{\cosh^2(\pi nL/W)}$

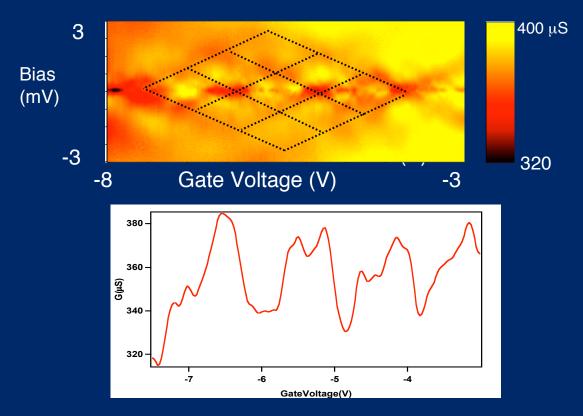
$$\sigma_{\min} = G_{\min} \frac{L}{W} = \frac{4e^2}{h} \frac{L}{W} \sum_{n=0}^{N-1} T_n$$



Good agreement with data with no free parameters.

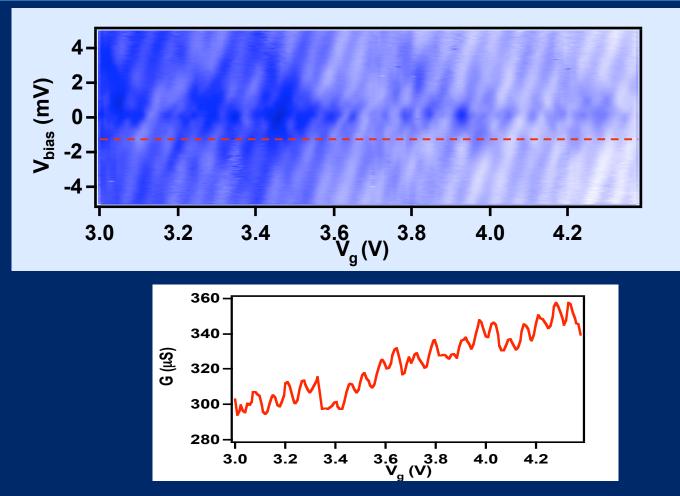
Charge Transport in Graphene Devices

Graphene Coupled to Normal Electrodes at 260mK (B= 40mT to suppress superconductivity in aluminum.)



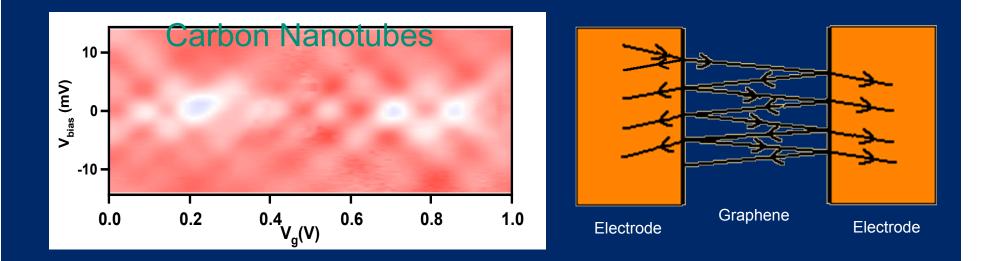
Periodic conductance oscillation as functions of both gate voltage and bias.

Charge Transport in Graphene Devices



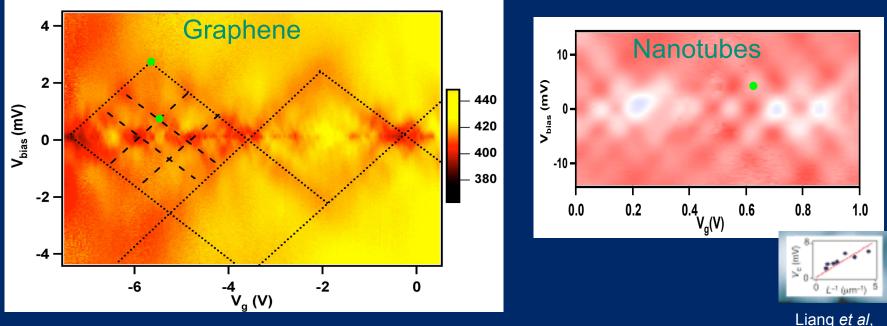
 Robust phenomena -- observed for both single and bi-layer devices, and for both hole- and electron-doped regimes.

Quantum Interference of Electron Waves in Graphene



Similar conductance oscillation observed in carbon nanotubes Liang et al, Nature, 2001.
Fabry-Perot resonant cavity -- interference of multiplyreflected electron and hole waves between partially transmitting electrodes.

Graphene as a Quantum Billiard



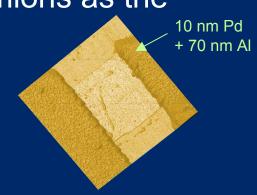
Liang *et al*, 2001.

- More than 1 period was observed in graphene devices
- Characteristic energy scale $E_o = hv_F/2L$
 - Nanotubes: $L \sim$ inter-electrode spacing for nanotubes
 - Graphene: $L \sim ?$
- Electron paths in 2D graphene are not well-defined as in 1D nanotubes
- Smallest $E_o \sim 0.7 \text{ meV} \rightarrow \text{Charge coherence length} > 5 \,\mu\text{m}$ in graphene

Graphene Coupled to Superconducting Electrodes

Josephson junction with massless Dirac fermions as the normal metal

Novel phenomena expected: •Specular Andreev reflection (Beenakker, *PRL* 2006, Titov and Beenakker, *PRB* 2006)



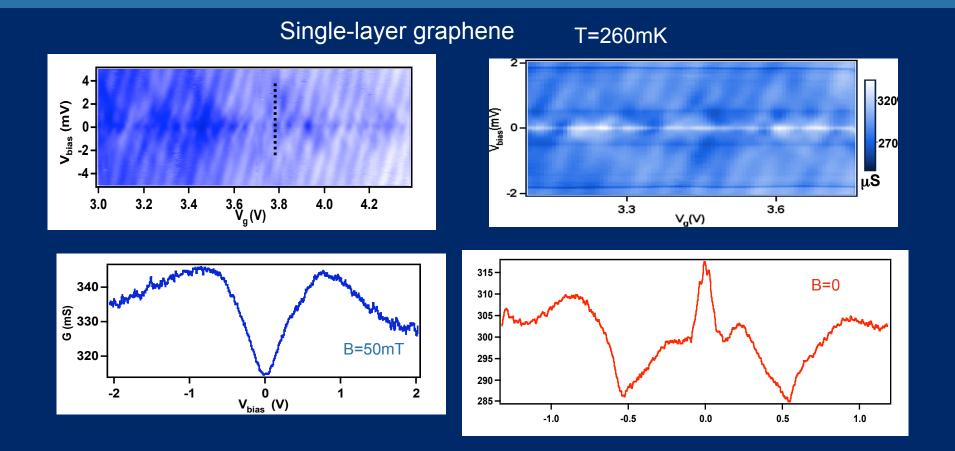
•Excitation gap of graphene channel and novel propagating modes of Andreev electrons (Titov, Ossipov and Beenakker, 2006)

•Oscillation of tunneling probability with barrier width (Sengupta 2006)

January 11, 2007

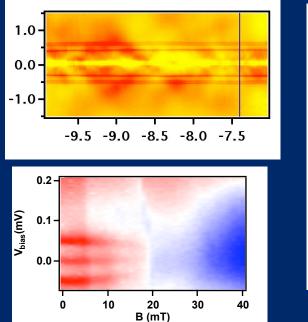
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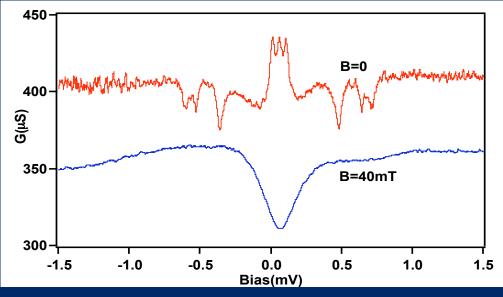
Superconducting Proximity Effect



• Enhanced conductance at small V_{bias} < 200 μ V – superconducting proximity effect.

Proximity Effect at Low-bias

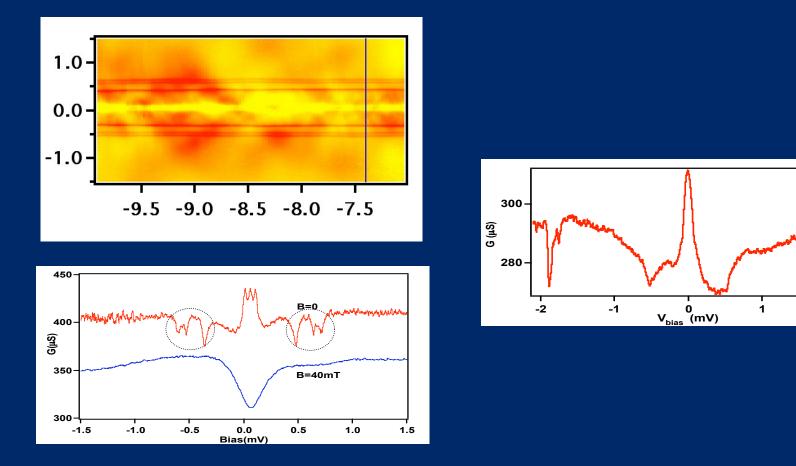




- the conductance display a single peak at zero bias
- two additional side peaks at ~ 50μ V(sub-gap structure)
- position of peaks suppressed by magnetic field

Similar low-bias peaks reported in superconductor-contacted few layer graphenes. (Shalos *et al*, cond-mat/0612058)

Anomalous Above-gap Conductance Dips

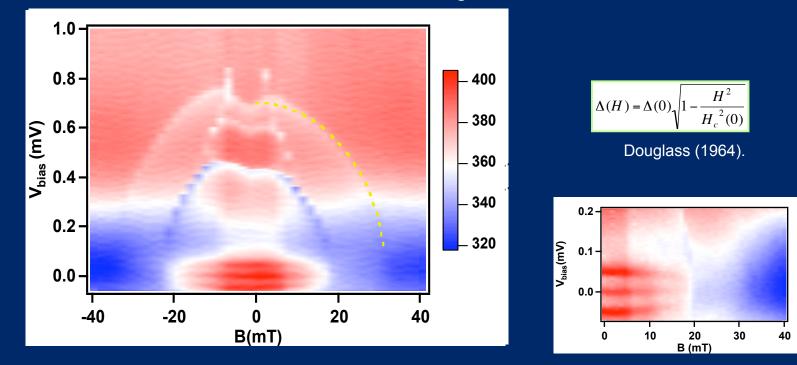


- Anomalous Conductance Dips at $V_{bias} >> \Delta$ (~200 μ V for AI)
- Independent of gate voltage
- Not observed for devices with resistance >20 k Ω

2

Dependence in Magnetic Field

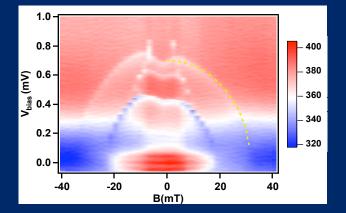
Conductance as functions of bias and magnetic field



• Zero-bias conductance peaks suppressed at 19mT.

• Above-gap Conductance dips suppressed at 32mT. V(H) curve resembles that of a superconducting gap, with $H_c \sim 32$ mT.

Signature of novel superconductors?



Superconductivity in metal coated graphene

B. Uchoa^{*}, and A. H. Castro Neto Physics Department, Boston University, 590 Commonwealth Ave., Boston, MA 02215

We show that graphene, a single atomic layer of graphite, can become a superconductor when coated with a dilute layer of alkali metal. We propose a microscopic mechanism of superconductivity based on the attraction of electrons in graphene mediated by a screeened acoustic plasmon of the metal. We discuss the phase diagram for superconductivity in graphene, which has two different singlet superconducting phases: with symmetry s and p + ip wave.

(2006)

- Plasmon-mediated superconductivity predicted in graphene coated with metal atoms.
- Possible signature of such superconductivity in graphene contacted with Pd
- Experiments underway for further investigation

Conclusion and Future Work

We investigated phase coherent transport of charges in single and bi-layer graphene devices.

✓ Minimum conductivity of a wide strip of graphene approaches theoretical value of $4e^2/\pi h$.

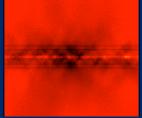
- ? Devices with different aspect ratios
- ? Devices with different inter-electrode spacings
- ? Conductivity in bi-layer graphene

 Graphene as quantum billiards -- Ballistic, phase coherent transport with coherence length >5 μm.

- ? Chaotic trajectory, open billiards
- ? Complicated patterns at Dirac point

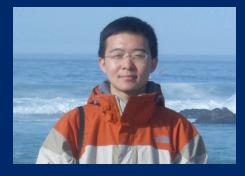
Proximity effect observed in graphene coupled to superconductors

- ? Supercurrent (recently observed by Morpurgo group at Delft)
- ? Specular Andreev reflection
- ? Excitation gap
- ? Plasmon-mediated superconductivity



Acknowldegement

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Feng Miao Undergraduate Student



Sitara Wijeratne

Postdoctoral Fellows





Yong Zhang

Ulas Coskun